NSN 5962-01-116-5780

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View Online at https://aerobasegroup.com/nsn/5962-01-116-5780

Body Length:
Between 0.880 inches and 0.930 inches
Body Width:
Between 0.265 inches and 0.300 inches
Body Height:
Between 0.155 inches and 0.175 inches
Maximum Power Dissipation Rating:
307.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
6930-01-102-2345 36378
Features Provided:
Hermetically sealed and monolithic and positive outputs and programmable and w/enable
Inclosure Material:
Ceramic and glass
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
10 input
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
5.5 volts power source
Time Rating Per Chacteristic:
40.00 nanoseconds propagation delay time, low to high level output and 40.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Rom
Memory Capacity:
Unknown
Terminal Type And Quantity:
16 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:

Yes - demil/mli

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